

KEYNOTE TALK 10

BAETE ACCREDITATION PREPARATION - PROGRAM'S PERSPECTIVE

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ABSTRACT

BAETE accreditation process is voluntary. An institution submits an application for the accreditation of an eligible program without persuasion or pressure. A program may face many challenges when it prepares for accreditation. The talk is focused on helping the programs in that preparation by discussing the best practices. A program needs to identify the gaps between the current practice it follows and the BAETE proposed accreditation process. This talk will help a program to identify the processes it should develop and practice in the way of applying for BAETE accreditation. The talk will introduce the BAETE accreditation process by discussing the major steps of accreditation. It will also guide a new program or an existing program applying under manual v2.1 for the first time to the starting point of the preparation process, i.e., the manual, Self-Assessment Report (SAR) template, Evaluation Team (ET) Report template, etc. Special emphasis will be given in attaining different outcomes and demonstrating complex engineering problems and activities in teaching, learning and assessment. Next, documents needed for writing the SAR will be presented. Finally, the talk will be concluded with a discussion on taking preparation for the ET visit.



Salekul Islam is a professor and also the Head of the Computer Science and Engineering Department at United International University (UIU), Bangladesh. Prior to joining UIU, he served as an Assistant Professor at North South University, also located in Bangladesh. In addition, he was an FRQNT Postdoctoral Fellow at the Énergie, Matériaux et Télécommunications (EMT) center of Institut national de la recherche scientifique (INRS) in Montréal, where he was advised by Dr. Jean-Charles Grégoire. Professor Islam earned his PhD from the Computer Science and Software Engineering Department of Concordia University in June 2008, under the supervision of Dr. J. William Atwood.